Features

- Fast read access time 90ns
- Dual voltage range operation
 - Unregulated battery power supply range, 2.7V to 3.6V, or
 - Standard power supply range, $5V\pm10\%$
- Pin compatible with JEDEC standard Atmel[®] AT27C1024
- Low-power CMOS operation
 - 20µA max standby (less than 1µA, typical) for V_{CC} = 3.6V
 - 36mW max active at 5MHz for V_{CC} = 3.6V
- JEDEC standard surface mount package
 44-lead PLCC
- High-reliability CMOS technology
 - 2,000V ESD protection
 - 200mA latchup immunity
- Rapid programming algorithm 100µs/word (typical)
- CMOS- and TTL-compatible inputs and outputs
 - JEDEC standard for LVTTL and LVBO
- Integrated product identification code
- Industrial temperature range

1. Description

The Atmel AT27BV1024 is a high-performance, low-power, low-voltage, 1,048,576-bit, one-time programmable, read-only memory (OTP EPROM) organized as 64K by 16 bits. It requires only one supply in the range of 2.7V to 3.6V in normal read mode operation. The x16 organization makes this part ideal for portable and handheld 16- and 32-bit microprocessor-based systems using either regulated or unregulated battery power.

The Atmel innovative design techniques provide fast speeds that rival 5V parts, while keeping the low power consumption of a 3V supply. At $V_{CC} = 2.7V$, any word can be accessed in less than 90ns. With a typical power dissipation of only 18mW at 5MHz and $V_{CC} = 3V$, the AT27BV1024 consumes less than one-fifth the power of a standard, 5V EPROM.

Standby mode supply current is typically less than 1μ A at 3V. The AT27BV1024 simplifies system design and stretches battery lifetime even further by eliminating the need for power supply regulation.

The AT27BV1024 is available in an industry-standard, JEDEC-approved, one-time programmable (OTP) PLCC package. All devices feature two-line control (\overline{CE} , \overline{OE}) to give designers the flexibility to prevent bus contention.

The AT27BV1024 operating with V_{CC} at 3.0V produces TTL-level outputs that are compatible with standard TTL logic devices operating at V_{CC} = 5.0V. At V_{CC} = 2.7V, the part is compatible with JEDEC-approved, low-voltage battery operation (LVBO) interface specifications. The device is also capable of standard, 5V operation making it ideally suited for dual supply range systems or card products that are pluggable in both 3V and 5V hosts.

The AT27BV1024 has additional features to ensure high quality and efficient production use. The rapid programming algorithm reduces the time required to program the part and guarantees reliable programming. Programming time is typically only 100 µs/word. The integrated product identification code electronically identifies the device and





1Mb (64K x 16) Unregulated Battery Voltage, High-speed, One-time Programmable, Read-only Memory

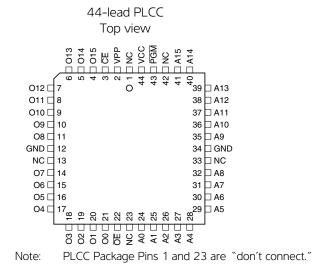
Atmel AT27BV1024



manufacturer. This feature is used by industry-standard programming equipment to select the proper programming algorithms and voltages. The AT27BV1024 programs in exactly the same way as a standard, 5V Atmel AT27C1024, and uses the same programming equipment.

2. Pin configurations

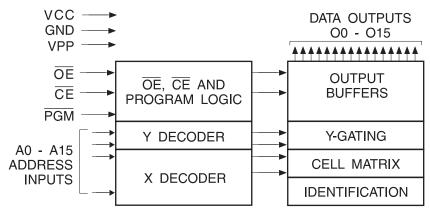
Function
Addresses
Outputs
Chip enable
Output enable
Program strobe
No connect



Note: Both GND pins must be connected.

3. System considerations

Switching between active and standby conditions via the chip enable pin may produce transient voltage excursions. Unless accommodated by the system design, these transients may exceed datasheet limits, resulting in device non-conformance. At a minimum, a 0.1μ F, high-frequency, low inherent inductance, ceramic capacitor should be utilized for each device. This capacitor should be connected between the V_{CC} and ground terminals of the device, as close to the device as possible. Additionally, to stabilize the supply voltage level on printed circuit boards with large EPROM arrays, a 4.7μ F bulk electrolytic capacitor should be utilized, again connected between the V_{CC} and ground terminals. This capacitor should be positioned as close as possible to the point where the power supply is connected to the array.





4. Absolute maximum ratings*

Temperature under bias55°C to +125°C
Storage temperature
Voltage on any pin with respect to ground2.0V to +7.0V ⁽¹⁾
Voltage on A9 with respect to ground2.0V to +14.0V ⁽¹⁾
V _{PP} supply voltage with respect to ground2.0V to +14.0V ⁽¹⁾
Noto: 1 Minimum voltago is 0.6 // DC which may under

- *NOTICE: Stresses beyond those listed under "Absolute maximum ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
- Note: 1. Minimum voltage is -0.6V DC , which may undershoot to -2.0V for pulses of less than 20ns. Maximum output pin voltage is V_{CC} + 0.75V DC, which may overshoot to +7.0V for pulses of less than 20ns.

5. AC and DC characteristics

Mode/Pin	CE	ŌĒ	PGM	Ai	V _{PP}	V _{cc}	Outputs
Read ⁽²⁾	V _{IL}	VIL	X ⁽¹⁾	Ai	Х	V _{CC}	D _{OUT}
Output disable ⁽²⁾	Х	V _{IH}	X	Х	Х	V _{CC}	High Z
Standby ⁽²⁾	V _{IH}	X	Х	Х	X ⁽⁵⁾	V _{CC}	High Z
Rapid program ⁽³⁾	V _{IL}	V _{IH}	V _{IL}	Ai	V _{PP}	V _{CC}	D _{IN}
PGM verify ⁽³⁾	VIL	VIL	VIH	Ai	V _{PP}	V _{CC}	D _{OUT}
PGM inhibit ⁽³⁾	V _{IH}	X	Х	Х	V _{PP}	V _{CC}	High Z
Product identification ⁽³⁾⁽⁵⁾	V _{IL}	V _{IL}	X	$A9 = V_{H}^{(4)}$ $A0 = V_{IH} \text{ or } V_{IL}$ $A1 - A15 = V_{IL}$	V _{cc}	V _{CC}	Identification code

Table 5-1. Operating modes

Notes: 1. X can be V_{IL} or V_{IH} .

2. Read, output disable, and standby modes require 2.7V \leq V_{CC} \leq 3.6V or 4.5V \leq V_{CC} \leq 5.5V.

3. Refer to programming characteristics. Programming modes require $V_{CC} = 6.5V$.

4. $V_{H} = 12.0 \pm 0.5 V.$

5. Two identifier words may be selected. All Ai inputs are held low (V_{IL}) except A9, which is set to $V_{H'}$ and A0, which is toggled low (V_{IL}) to select the manufacturer's identification word and high (V_{IH}) to select the device code word.

Table 5-2. DC and AC operating conditions for read oepration

	Atmel AT27BV1024-90
Industrial operating temperature (case)	-40°C - 85°C
	2.7V to 3.6V
V _{CC} power supply	5V ± 10%





Table 5-3. DC and operating characteristics for read operation

Symbol	Parameter	Condition	Min	Max	Units
V _{CC} = 2.7V	/ to 3.6V			·	
ILI	Input load current	$V_{IN} = OV$ to V_{CC}		±1	μA
ILO	Output leakage current	$V_{OUT} = 0V$ to V_{CC}		±5	μA
(2)	V _{PP} ⁽¹⁾ read/standby current	V _{PP} = V _{CC}		10	μA
) ((1) stars discussion to	I_{SB1} (CMOS), $\overline{CE} = V_{CC} \pm 0.3V$		20	μA
I _{SB}	V _{CC} ⁽¹⁾ standby current	I_{SB2} (TTL), \overline{CE} = 2.0 to V_{CC} + 0.5V		100	μA
I _{cc}	V _{CC} active current	f = 5MHz, I_{OUT} = 0mA, \overline{CE} = V_{IL} , V_{CC} = 3.6V		8	mA
		V _{CC} = 3.0 to 3.6V	-0.6	0.8	V
V _{IL}	Input low voltage	V _{CC} = 2.7 to 3.6V	-0.6	0.2 x V _{CC}	V
		V _{CC} = 3.0 to 3.6V	2.0	V _{CC} + 0.5	V
V _{IH}	Input high voltage	$V_{CC} = 2.7 \text{ to } 3.6 \text{V}$	0.7 x V _{CC}	V _{CC} + 0.5	V
		I _{OL} = 2.0mA		0.4	V
V _{OL} Output low voltage	Ι _{OL} = 100μΑ		0.2	V	
	Ι _{ΟL} = 20μΑ		0.1	V	
		I _{OH} = -2.0mA	2.4		V
/ _{OH} Output high voltage	I _{OH} = -100μA	V _{CC} - 0.2		V	
		I _{OH} = -20µА	V _{CC} - 0.1		V
V _{CC} = 4.5V	/ to 5.5V				
ILI	Input load current	$V_{IN} = OV$ to V_{CC}		±1	μA
I _{LO}	Output leakage current	$V_{OUT} = 0V$ to V_{CC}		±5	μA
l _{PP1} (2)	V _{PP} ⁽¹⁾ read/standby current	V _{PP} = V _{CC}		10	μA
		I_{SB1} (CMOS), $\overline{CE} = V_{CC} \pm 0.3V$		100	μA
I _{SB}	V _{CC} ⁽¹⁾ standby current	I_{SB2} (TTL), \overline{CE} = 2.0 to V_{CC} + 0.5V		1	mA
I _{cc}	V _{CC} active current	$f = 5MHz$, $I_{OUT} = 0mA$, $\overline{CE} = V_{IL}$		30	mA
V _{IL}	Input low voltage		-0.6	0.8	V
V _{IH}	Input high voltage		2.0	V _{CC} + 0.5	V
V _{OL}	Output low voltage	I _{OL} = 2.1mA		0.4	V
V _{OH}	Output high voltage	I _{OH} = -400μA	2.4		V

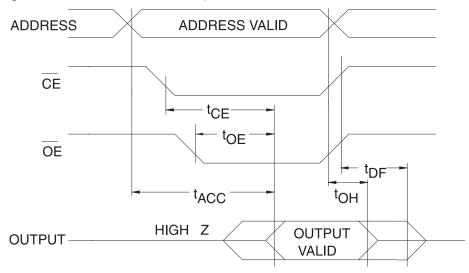
Notes: 1. V_{CC} must be applied simultaneously with or before V_{PP} , and removed simultaneously with or after V_{PP} .

2. V_{PP} may be connected directly to $V_{CC'}$ except during programming. The supply current would then be the sum of I_{CC} and I_{PP} .

Table 5-4. AC characteristics for read operation

			Atmel AT2	7BV1024-90	
Symbol	Parameter	Condition	Min	Max	Unit
t _{ACC} ⁽³⁾	Address to output delay	$\overline{CE} = \overline{OE} \\ = V_{IL}$		90	ns
t _{CE} ⁽²⁾	CE to output delay	$\overline{OE} = V_{IL}$		90	ns
t _{OE} ⁽²⁾⁽³⁾	OE to output delay	$\overline{CE} = V_{IL}$		30	ns
t _{DF} ⁽⁴⁾⁽⁵⁾	OE or CE High to output float, whichever occurred first			30	ns
t _{OH}	Output hold from address, CE or OE, whichever occurred first		0		ns

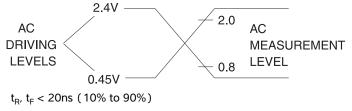
Figure 5-1. AC waveforms for read operation⁽¹⁾



Note: 1. Timing measurement references are 0.8V and 2.0V. Input AC drive levels are 0.45V and 2.4V, unless otherwise specified.

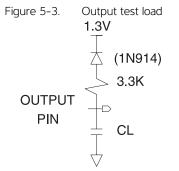
- 2. \overline{OE} may be delayed up to t_{CE} t_{OE} after the falling edge of \overline{CE} without impact on t_{CE} .
- 3. $\overline{\text{OE}}$ may be delayed up to t_{ACC} t_{OE} after the address is valid without impact on t_{ACC} .
- 4. This parameter is only sampled, and is not 100% tested.
- 5. Output float is defined as the point when data is no longer driven.
- 6. When reading an Atmel AT27BV1024, a 0.1 μ F capacitor is required across V_{CC} and ground to suppress spurious voltage transients.











Note: CL = 100pF including jig capacitance.

Table 5-5.Pin capacitance

 $f = 1MHz T = 25°C^{(1)}$

Symbol	Тур	Max	Units	Conditions
C _{IN}	4	10	pF	$V_{IN} = OV$
C _{OUT}	8	12	pF	$V_{OUT} = 0V$

Note: 1. Typical values for nominal supply voltage. This parameter is only sampled, and is not 100% tested.

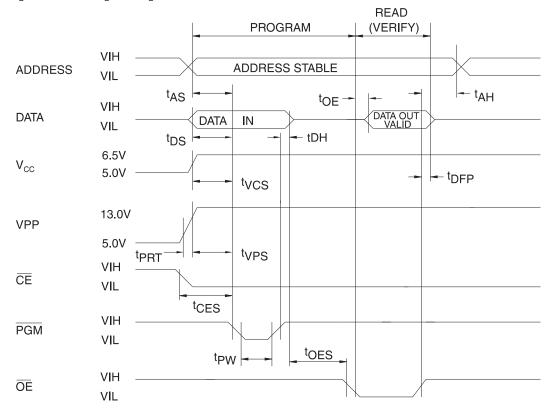


Figure 5-4. Programming waveforms⁽¹⁾

Note: 1. The input timing reference is 0.8V for $V_{\rm IL}$ and 2.0V for $V_{\rm IH}$

- 2. t_{OE} and t_{DEP} are characteristics of the device, but must be accommodated by the programmer.
- 3. When programming the Atmel AT27BV1024 a 0.1μ F capacitor is required across V_{PP} and ground to suppress spurious voltage transients.

Table 5-6.DC programming characteristics

 $T_A = 25 \pm 5^{\circ}$ C, $V_{CC} = 6.5 \pm 0.25$ V, $V_{PP} = 13.0 \pm 0.25$ V

			L	Limits		
Symbol	Parameter	Test conditions	Min	Max	Units	
I _{LI}	Input load current	$V_{IN} = V_{IL}, V_{IH}$		±10	μA	
V _{IL}	Input low level		-0.6	0.8	V	
V _{IH}	Input high level		2.0	V _{CC} + 0.1	V	
V _{OL}	Output low voltage	I _{OL} = 2.1mA		0.4	V	
V _{OH}	Output high voltage	I _{OH} = -400μA	2.4		V	
I _{CC2}	V _{CC} supply current (program and verify)			50	mA	
I _{PP2}	V _{PP} supply current	$\overline{CE} = \overline{PGM} = V_{IL}$		30	mA	
V _{ID}	A9 product identification voltage		11.5	12.5	V	

Table 5-7.AC programming characteristics

 T_A = 25 \pm 5° C, V_{CC} = 6.5 \pm 0.25V, V_{PP} = 13.0 \pm 0.25V

			Lin	nits	
Symbol	Parameter	Test conditions ⁽¹⁾	Min	Max	Units
t _{AS}	Address setup time		2		μs
t _{CES}	CE setup time	Input rise and fall times:	2		μs
t _{OES}	OE setup time	(10% to 90%) 20ns	2		μs
t _{DS}	Data setup time		2		μs
t _{AH}	Address hold time	Input pulse levels:	0		μs
t _{DH}	Data hold time	0.45V to 2.4V	2		μs
t _{DFP}	$\overline{\text{OE}}$ high to output float delay ⁽²⁾	Input timing reference level:	0	130	ns
t _{VPS}	V _{PP} setup time	0.8V to 2.0V	2		μs
t _{VCS}	V _{CC} setup time		2		μs
t _{PW}	PGM program pulse width ⁽³⁾	Output timing reference level:	95	105	μs
t _{OE}	Data valid from OE	0.8V to 2.0V		150	ns
t _{PRT}	V _{PP} pulse rise time during programming		50		ns

Notes: 1. V_{CC} must be applied simultaneously with or before V_{PP} and removed simultaneously with or after V_{PP} .

2. This parameter is only sampled, and is not 100% tested. Output float is defined as the point where data is no longer driven. See timing diagram.

3. Program pulse width tolerance is $100\mu sec \pm 5\%$.

Table 5-6. The Alther ATZ7 BV 1024 Integrated product identification code	Table 5-8.	The Atmel AT27BV1024 integrated product identification code ⁽¹⁾
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					Pi	ns					
Codes	AO	015- 08	07	O6	O5	04	O3	02	O1	00	Hex data
Manufacturer	0	0	0	0	0	1	1	1	1	0	001E
Device type	1	0	1	1	1	1	0	0	0	1	00F1

Note: 1. The Atmel AT27BV1024 has the same product identification code as the Atmel AT27C1024. Both are programming compatible

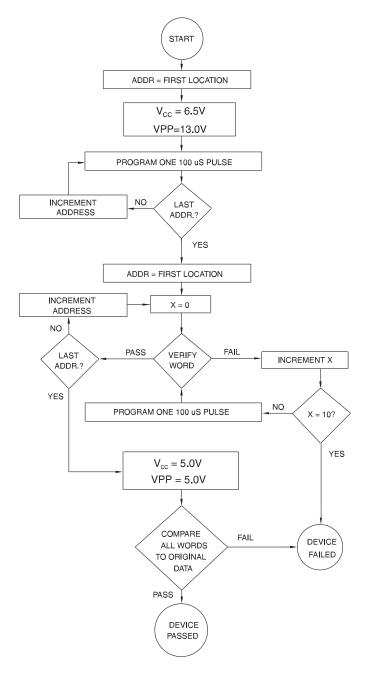


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6. Rapid programming algorithm

A 100 μ s PGM pulse width is used to program. The address is set to the first location. V_{CC} is raised to 6.5V and V_{PP} is raised to 13.0V. Each address is first programmed with one 100 μ s PGM pulse without verification. Then a verification/reprogramming loop is executed for each address. In the event a word fails to pass verification, up to 10 successive 100 μ s pulses are applied with a verification after each pulse. If the word fails to verify after 10 pulses have been applied, the part is considered failed. After the word verifies properly, the next address is selected until all have been checked. V_{PP} is then lowered to 5.0V and V_{CC} to 5.0V. All words are read again and compared with the original data to determine if the device passes or fails.

Figure 6-1. Rapid programming algorithm



7. Ordering information

Green package (Pb/hailde-free)

t	t _{ACC}	I _{CC} (mA)					
((ns)	Active	Standby	Atmel ordering code	Lead finish	Package	Operation range
	90	8	0.02	AT27BV1024-90JU	Matte tin	44J	Industrial (-40°C to 85°C)

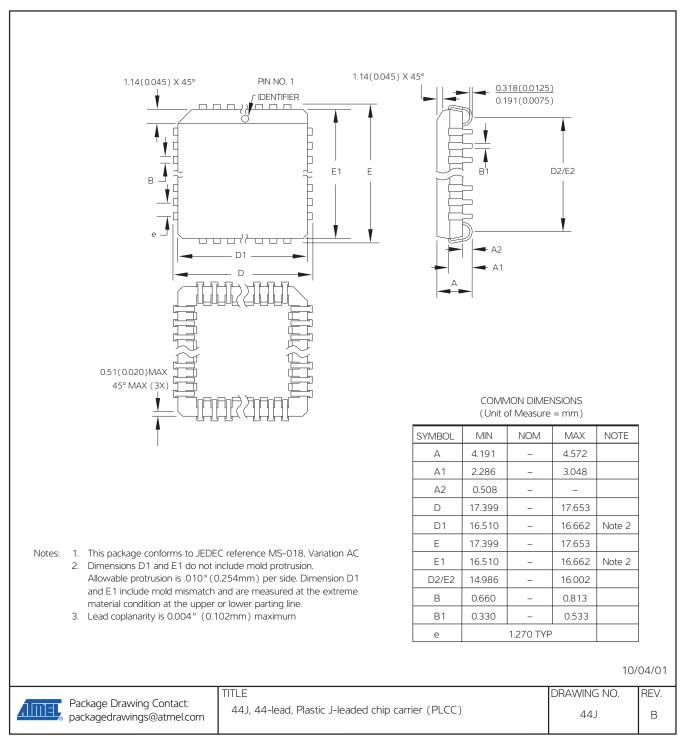
Package type					
44J 44-lead, plastic, J-leaded chip carrier (PLCC)					





8. Packaging Information

44J – PLCC



9. Revision history

Doc. rev.	Date	Comments	
0631F	04/2011	Remove VSOP package Add lead finish to ordering information Change 120ns to 90ns	
0631E	12/2007		





Atmel Corporation

2325 Orchard Parkway San Jose, CA 95131 USA Tel: (+1) (408) 441-0311 Fax: (+1) (408) 487-2600 www.atmel.com Atmel Asia Limited Unit 01-5 & 16, 19F BEA Tower, Millennium City 5 418 Kwun Tong Road Kwun Tong, Kowloon HONG KONG Tel: (+852) 2245-6100 Fax: (+852) 2722-1369

Atmel Munich GmbH

Business Campus Parkring 4 D-85748 Garching b. Munich GERMANY Tel: (+49) 89-31970-0 Fax: (+49) 89-3194621

Atmel Japan

9F, Tonetsu Shinkawa Bldg. 1-24-8 Shinkawa Chuo-ku, Tokyo 104-0033 JAPAN **Tel:** (+81) (3) 3523-3551 **Fax:** (+81) (3) 3523-7581

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